

# 8-Pin DIP Low Input Current High Gain Split Darlington Optocouplers

# Single-Channel: 6N138M, 6N139M Dual-Channel: HCPL2730M, HCPL2731M

#### **Description**

The single-channel, 6N138M, 6N139M and dual-channel HCPL2730M, HCPL2731M optocouplers consist of an AlGaAs LED optically coupled to a high gain split darlington photodetector.

The split darlington configuration separating the input photodiode and the first stage gain from the output transistor permits lower output saturation voltage and higher speed operation than possible with conventional darlington phototransistor optocoupler. In the dual channel devices, HCPL2730M and HCPL2731M, an integrated emitter–base resistor provides superior stability over temperature.

The combination of a very low input current of 0.5 mA and a high current transfer ratio of 2000% makes this family particularly useful for input interface to MOS, CMOS, LSTTL and EIA RS232C, while output compatibility is ensured to CMOS as well as high fan–out TTL requirements. An internal noise shield provides exceptional common mode rejection of  $10 \, \text{kV/us}$ .

#### **Features**

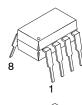
- Low Current − 0.5 mA
- Superior CTR 2000%
- Superior CMR 10 kV/μs
- CTR Guaranteed 0 to 70°C
- Dual Channel HCPL2730M, HCPL2731M
- Safety and Regulatory Approvals
- UL1577, 5,000 VAC<sub>RMS</sub> for 1 Minute
- DIN EN/IEC60747-5-5
- These are Pb-Free Devices

#### **Applications**

- Digital Logic Ground Isolation
- Telephone Ring Detector
- EIA-RS-232C Line Receiver
- High Common Mode Noise Line Receiver
- μP Bus Isolation
- Current Loop Receiver



PDIP8 6.6x3.81, 2.54P CASE 646BW



PDIP8 9.655x6.6, 2.54P CASE 646CQ



PDIP8 GW CASE 709AC

#### MARKING DIAGRAM

6N138 VXXYYB

6N138 = De

= Device Number

- DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
- XX = Two-Digit Year Code, e.g., '16'
- Y = Two-Digit Work Week, Ranging from
  - '01' to '53'
- B = Assembly Package Code

### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 11 of this data sheet.

#### **Related Resources**

1

- https://www.onsemi.com/products/interfaces/ high-performance-optocouplers/high-performance-transistor-optocouplers
- <a href="https://www.onsemi.com/products/interfaces/">https://www.onsemi.com/products/interfaces/</a>
   <a href="https://www.onsemi.com/products/">https://www.onsemi.com/products/</a>
   <a href="https://www.ons
- <a href="https://www.onsemi.com/products/interfaces/high-performance-optocouplers/high-performance-transistor-optocouplers/hcpl0731">https://www.onsemi.com/products/interfaces/high-performance-optocouplers/high-performance-transistor-optocouplers/hcpl0731</a>

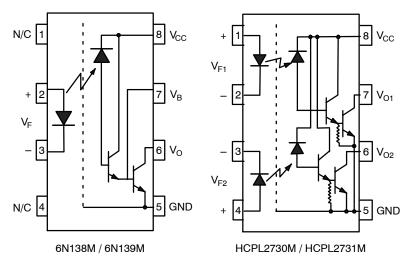


Figure 1. Schematics

**SAFETY AND INSULATION RATINGS** (As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated	<150 V <sub>RMS</sub>	I–IV
Mains Voltage	<300 V <sub>RMS</sub>	I–IV
	<450 V <sub>RMS</sub>	I–III
	<600 V <sub>RMS</sub>	I–III
	<1,000 V <sub>RMS</sub> (Option T, TS)	I–III
Climatic Classification	40/100/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index	175	

Symbol	Parameter	Value	Unit
$V_{PR}$	Input–to–Output Test Voltage, Method A, $V_{IORM}$ x 1.6 = $V_{PR}$ , Type and Sample Test with $t_m$ = 10 s, Partial Discharge < 5 pC		V <sub>peak</sub>
	Input–to–Output Test Voltage, Method B, $V_{IORM}$ x 1.875 = $V_{PR}$ , 100% Production Test with $t_m$ = 1 s, Partial Discharge < 5 pC	2,651	V <sub>peak</sub>
V <sub>IORM</sub>	Maximum Working Insulation Voltage	1,414	V <sub>peak</sub>
V <sub>IOTM</sub>	Highest Allowable Over-Voltage	6,000	V <sub>peak</sub>
	External Creepage	≥8.0	mm
	External Clearance	≥7.4	mm
	External Clearance (for Option TV, 0.4" Lead Spacing)	≥10.16	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.5	mm
T <sub>S</sub>	Case Temperature (Note 1)	150	°C
I <sub>S,INPUT</sub>	Input Current (Note 1)	200	mA
P <sub>S,OUTPUT</sub>	Output Power (Duty Factor ≤ 2.7%) (Note 1)	300	mW
R <sub>IO</sub>	Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V (Note 1)	>10 <sup>9</sup>	Ω

<sup>1.</sup> Safety limit value - maximum values allowed in the event of a failure.

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Output Power Dissipation Per Channel

 $P_{\mathsf{O}}$ 

Symbol	Parameter	Device	Value	Unit
T <sub>STG</sub>	Storage Temperature		-40 to +125	°C
T <sub>OPR</sub>	Operating Temperature		-40 to +100	°C
TJ	Junction Temperature		-40 to +125	°C
T <sub>SOL</sub>	Lead Solder Temperature		260 for 10 s	°C
EMITTER				
I <sub>F</sub> (avg)	DC/Average Forward Input Current Per Channel	All	20	mA
I <sub>F</sub> (pk)	Peak Forward Input Current Per Channel (50% Duty Cycle, 1 ms P.W.)	All	40	mA
I <sub>F</sub> (trans)	Peak Transient Input Current Per Channel (≤1 μs P.W., 300 pps)	All	1	Α
V <sub>R</sub>	Reverse Input Voltage Per Channel	All	5	V
$P_{D}$	Input Power Dissipation Per Channel (Note 2)	All	35	mW
DETECTOR				
I <sub>O</sub> (avg)	Average Output Current Per Channel	All	60	mA
V <sub>ER</sub>	Emitter-Base Reverse Voltage	6N138M, 6N139M	0.5	V
$V_{CC}, V_{O}$	Supply Voltage, Output Voltage	6N138M, HCPL2730M	-0.5 to 7.0	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. No derating required for devices operated within the T<sub>OPR</sub> specification (6N138M and 6N139M only).

6N139M, HCPL2731M

ΑII

-0.5 to 18.0

100

mW

#### **ELECTRICAL CHARACTERISTICS**

Symbol	Symbol Parameter De		Test Conditions	Min	Тур	Max	Unit		
INDIVIDUAL COMPONENT CHARACTERISTICS (V <sub>CC</sub> = 5.0 V, T <sub>A</sub> = 0°C to 70°C unless otherwise specified. Typical value is measured									
at $T_{\Lambda} = 25^{\circ}$	C.)								

EMITTER									
V <sub>F</sub>	Input Forward Voltage	All	I <sub>F</sub> = 1.6 mA, T <sub>A</sub> = 25°C		-	1.30	1.70	V	
			I <sub>F</sub> = 1.6 mA		-	-	1.75		
BV <sub>R</sub>	Input Reverse Breakdown Voltage	All	I <sub>R</sub> = 10 μA, 7	<sub>A</sub> = 25°C	5.0	19.0	-	V	
ΔV <sub>F</sub> / ΔT <sub>A</sub>	Temperature Coefficient of Forward Voltage	All	I <sub>F</sub> = 1.6 mA		_	-1.94	-	mV/°C	
DETECTO	DETECTOR								
I <sub>CCL</sub>	I <sub>CCL</sub> Logic Low Supply Current		I <sub>F</sub> = 1.6 mA, V <sub>CC</sub> = 18 V	V <sub>O</sub> = Open,	-	0.4	1.5	mA	
		HCPL2730M	V <sub>CC</sub> = 7 V	I <sub>F1</sub> = I <sub>F2</sub> = 1.6 mA,	-	1.25	3		
		HCPL2731M	V <sub>CC</sub> = 18 V	V <sub>O1</sub> = V <sub>O2</sub> = Open					
Іссн	Logic High Supply Current	6N138M, 6N139M	$I_F = 0$ mA, $V_O = Open$ , $V_{CC} = 18$ V		-	0.0003	10	μΑ	
		HCPL2730M	V <sub>CC</sub> = 7 V	$I_{F1} = I_{F2} = 0 \text{ mA},$ $V_{O1} = V_{O2} = \text{Open}$	-	0.0003	20		
		HCPL2731M	V <sub>CC</sub> = 18 V	v <sub>O1</sub> = v <sub>O2</sub> = Open					

#### TRANSFER CHARACTERISTICS

COUPLE	)						
CTR	Current Transfer Ratio (Note 3)	6N138M	$I_F = 1.6 \text{ mA}, V_O = 0.4 \text{ V},$	300	1600	-	%
	(Note 4)	HCPL2730M	V <sub>CC</sub> = 4.5 V		2400		
		6N139M	$I_F = 0.5 \text{ mA}, V_O = 0.4 \text{ V},$	400	2000	-	
		HCPL2731M	V <sub>CC</sub> = 4.5 V		3500		
		6N139M	$I_F = 1.6 \text{ mA}, V_O = 0.4 \text{ V},$	500	1600	-	
		HCPL2731M	V <sub>CC</sub> = 4.5 V		2400		
I <sub>OH</sub>	Logic High Output Current	6N138M	$I_F = 0 \text{ mA}, V_O = V_{CC} = 7 \text{ V}$	-	0.001	250	μΑ
		6N139M	$I_F = 0 \text{ mA}, V_O = V_{CC} = 18 \text{ V}$	-	0.0036	100	
		HCPL2731M					
V <sub>OL</sub>	Logic Low Output Voltage (Note 4)	6N138M	$I_F = 1.6 \text{ mA}, I_O = 4.8 \text{ mA},$	_	0.06	0.4	٧
	(Note 4)	HCPL2730M	V <sub>CC</sub> = 4.5 V		0.05		
		6N139M	$I_F = 0.5 \text{ mA}, I_O = 2 \text{ mA}, V_{CC} = 4.5 \text{ V}$	_	0.05	0.4	
		6N139M	$I_F = 1.6 \text{ mA}, I_O = 8 \text{ mA},$	-	0.093	0.4	
		HCPL2731M	V <sub>CC</sub> = 4.5 V		0.08		
	$ \begin{array}{c c} \hline & 6\text{N139M} & \text{I}_{\text{F}} = 5 \text{ mA, I}_{\text{O}} = 15 \text{ mA,} \\ \hline & \text{HCPL2731M} & \text{V}_{\text{CC}} = 4.5 \text{ V} \\ \end{array} $		-	0.13	0.4		
		HCPL2731M	VCC = 4.5 V		0.12		
		I <sub>F</sub> = 12 mA, I <sub>O</sub> = 24 mA,	-	0.18	0.4		
		HCPL2731M	V <sub>CC</sub> = 4.5 V		0.17		

#### **ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit				
SWITCHIN	WITCHING CHARACTERISTICS (V <sub>CC</sub> = 5.0 V, T <sub>A</sub> = 0°C to 70°C unless otherwise specified. Typical value is measured at T <sub>A</sub> = 25°C.)										
t <sub>PHL</sub>	Propagation Delay Time to	6N139M	$R_L = 270 \Omega$ , $I_F = 12 \text{ mA}$	-	0.2	2	μs				
	Logic LOW (Note 4) (Figure 14)	HCPL2730M, HCPL2731M	$R_L$ = 270 $\Omega$ , $I_F$ = 12 mA	-	0.5	3					
		6N138M	$R_L$ = 2.2 kΩ, $I_F$ = 1.6 mA	-	1.0	15					
		HCPL2730M, HCPL2731M	$R_L$ = 2.2 k $\Omega$ , $I_F$ = 1.6 mA	-	2.5	25					
		6N139M	$R_L = 4.7 \text{ k}\Omega, I_F = 0.5 \text{ mA}$	-	2.5	30					
		HCPL2731M	$R_L = 4.7 \text{ k}\Omega, I_F = 0.5 \text{ mA}$	-	8.4	120					
t <sub>PLH</sub>	Propagation Delay Time to	6N139M	$R_L$ = 270 Ω, $I_F$ = 12 mA	-	1.3	10	μs				
	Logic HIGH (Note 4) (Figure 14)	HCPL2730M, HCPL2731M	$R_L = 270 \Omega$ , $I_F = 12 \text{ mA}$	-	1.0	15					
		6N138M, HCPL2730M, HCPL2731M	$R_L$ = 2.2 k $\Omega$ , $I_F$ = 1.6 mA	-	7.3	50					
		6N139M, HCPL2731M	$R_L = 4.7 \text{ k}\Omega, I_F = 0.5 \text{ mA}$	-	13.6	90					
CM <sub>H</sub>	Common Mode Transient Immunity at Logic High (Note 5) (Figure 15)	All	$I_F = 0$ mA, $IV_{CM}I = 10$ $V_{P-P}$ , $R_L = 2.2$ k $\Omega$ , $T_A = 25$ °C	1,000	10,000	_	V/μs				
CM <sub>L</sub>	Common Mode Transient Immunity at Logic Low (Note 5) (Figure 15)	All	$\begin{split} I_F &= 1.6 \text{ mA, IV}_{CM}I = 10 \text{ V}_{P-P}, \\ R_L &= 2.2 \text{ k}\Omega, \text{ T}_A = 25^{\circ}\text{C} \end{split}$	1,000	10,000	-	V/μs				

#### ISOLATION CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified.)

V <sub>ISO</sub>	Withstand Insulation Test Voltage (Note 6) (Note 7)	All $RH \leq 50\%, T_A = 25^{\circ}C, \\ I_{I-O} \leq 10 \ \mu A, t = 1 \ min, f = 50 \ Hz$		5,000	_	-	VAC <sub>RMS</sub>
R <sub>I-O</sub>	Resistance (Input to Output) (Note 6)	All	V <sub>I-O</sub> = 500 V <sub>DC</sub>	-	10 <sup>11</sup>	ı	Ω
C <sub>I-O</sub>	Capacitance (Input to Output) (Note 6) (Note 8)	All	f = 1 MHz, V <sub>I-O</sub> = 0 V	-	1	1	pF
I <sub>I-I</sub>	Input-Input Insulation Leakage Current (Note 9)	HCPL2730M, HCPL2731M	RH $\leq$ 45%, $V_{I-I} = 500 V_{DC}$ , $t = 5 s$	-	0.005	ı	μΑ
$R_{I-I}$	Input-Input Resistance (Note 9)	HCPL2730M, HCPL2731M	V <sub>I-I</sub> = 500 V <sub>DC</sub>	-	10 <sup>11</sup>	-	Ω
C <sub>I-I</sub>	Input-Input Capacitance (Note 9)	HCPL2730M, HCPL2731M	f = 1 MHz	-	0.03	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 3. Current Transfer Ratio is defined as a ratio of output collector current, IO, to the forward LED input current, IF, times 100%.
- 4. Pin 7 open. (6N138M and 6N139M only)
- 5. Common mode transient immunity in logic HIGH level is the maximum tolerable (positive)  $dV_{cm}/dt$  on the leading edge of the common mode pulse signal  $V_{CM}$ , to assure that the output will remain in a logic HIGH state (i.e.,  $V_O > 2.0$  V). Common mode transient immunity in logic LOW level is the maximum tolerable (negative)  $dV_{cm}/dt$  on the trailing edge of the common mode pulse signal,  $V_{CM}$ , to assure that the output will remain in a logic LOW state (i.e.,  $V_O < 0.8$  V).
- 6. Device is considered a two terminal device: Pins 1, 2, 3 and 4 are shorted together and Pins 5, 6, 7 and 8 are shorted together.
- 7. 5000 VAC<sub>RMS</sub> for 1 minute duration is equivalent to 6000 VAC<sub>RMS</sub> for 1 second duration.
- 8. For dual channel devices,  $C_{I-O}$  is measured by shorting pins 1 and 2 or pins 3 and 4 together and pins 5 through 8 shorted together.
- 9. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

#### **ELECTRICAL CHARACTERISTICS** (continued)

(T<sub>A</sub> = 25°C unless otherwise specified.)

**Current Limiting Resistor Calculations:** 

 $R_{1} \text{ (Non-Invert)} = \frac{V_{CC1} - V_{DF} - V_{OL1}}{I_{F}}$  (eq. 1)

 $R_1 ext{ (Invert)} = \frac{V_{CC1} - V_{OH1} - V_{DF}}{I_F}$  (eq. 2)

 $R_2 = \frac{V_{CC2} - V_{OLX} (@ I_L - I_2)}{I_L}$ 

Where:

 $V_{CC1}$  = Input Supply Voltage  $V_{CC2}$  = Output Supply Voltage

V<sub>DF</sub> = Diode Forward Voltage

V<sub>OL1</sub> = Logic "0" Voltage of Driver V<sub>OH1</sub> = Logic "1" Voltage of Driver

I<sub>F</sub> = Diode Forward Current

V<sub>OLX</sub> = Saturation Voltage of Output Transistor

 $I_L$  = Load Current Through Resistor  $R_2$ 

I<sub>2</sub> = Input Current of Output Gate

INI	PUT		$R_2$ ( $\Omega$ ) @ OUTPUT CONFIGURATION						
	URATION	R <sub>1</sub> (Ω)	CMOS @ 5 V	CMOS @ 10 V	74XX	74LXX	74SXX	74LSXX	74HXX
CMOS @	NON-INV.	2000	1000	2200	750	1000	1000	1000	560
5 V	INV.	510	1						
CMOS @	NON-INV.	5100	1						
10 V	INV.	4700	1						
74XX	NON-INV.	2200	1						
	INV.	180	1						
74LXX	NON-INV.	1800	1						
	INV.	100	1						
74SXX	NON-INV.	2000	1						
	INV.	360	1						
74LSXX	NON-INV.	2000	1						
	INV.	180	1						
74HXX	NON-INV.	2000	1						
	INV.	180	1						

(eq. 3)

Figure 2. Resistor Values for Logic Interface

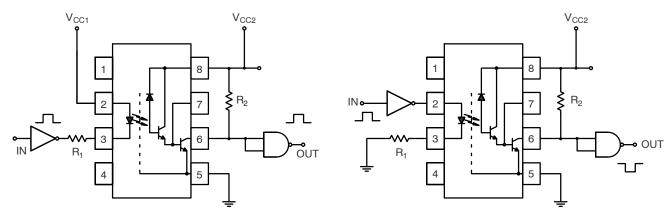


Figure 3. Non-Inverting Logic Interface

Figure 4. Inverting Logic Interface

#### **Typical Performance Curves**

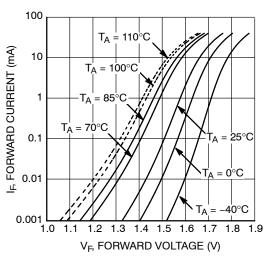


Figure 5. LED Forward Current vs. Forward Voltage

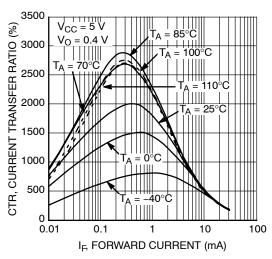


Figure 7. Current Transfer Ratio vs. Forward Current (6N138M / 6N139M Only)

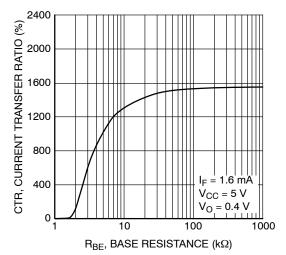


Figure 9. Current Transfer Ratio vs. Base-Emitter Resistance (6N138M / 6N139M Only)

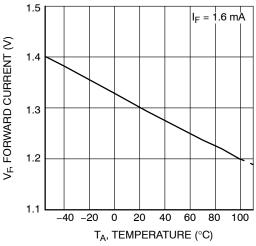


Figure 6. LED Forward Current vs. Temperature

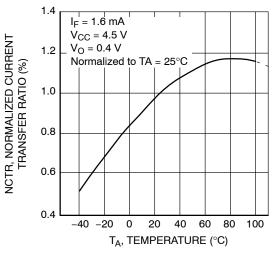


Figure 8. Normalized Current Transfer Ratio vs. Ambient Temperature (6N138M / 6N139M Only)

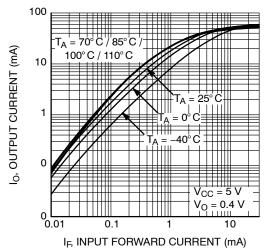


Figure 10. Output Current vs. Input Diode Forward Current (6N138M / 6N139M Only)



#### **Typical Performance Curves** (continued)

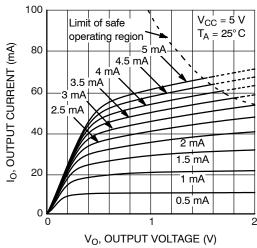


Figure 11. Output Current vs Output Voltage (6N138M / 6N139M Only)

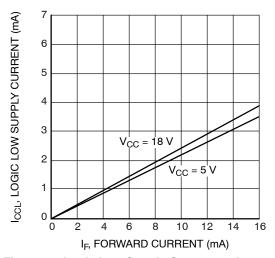


Figure 12. Logic Low Supply Current vs. Input Diode Forward Current (6N138M / 6N139M Only)

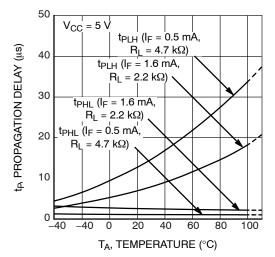


Figure 13. Propagation Delay vs. Temperature (6N138M / 6N139M Only)

#### **Test Circuits**

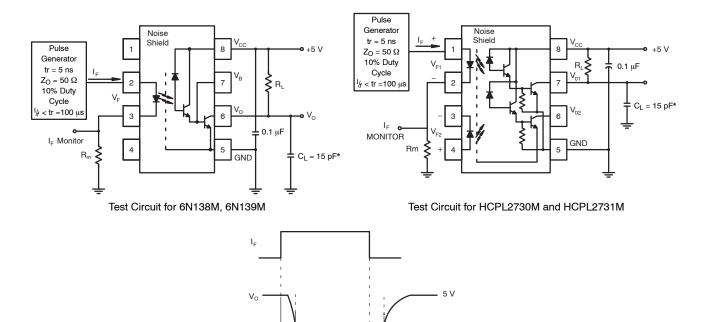


Figure 14. Switching Time Test Circuit

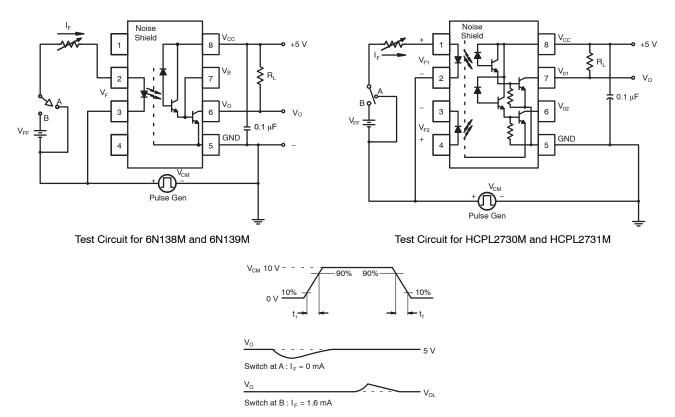
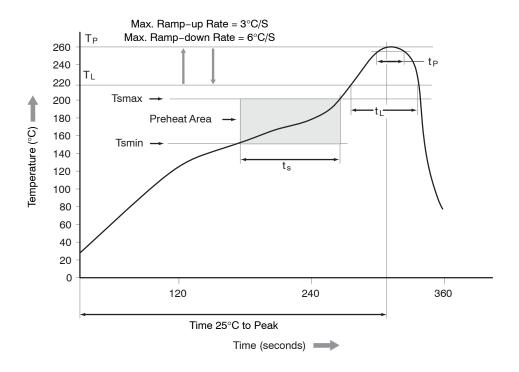


Figure 15. Common Mode Immunity Test Circuit

### **Reflow Profile**



Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60 – 120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

Figure 16. Reflow Profile

#### **ORDERING INFORMATION**

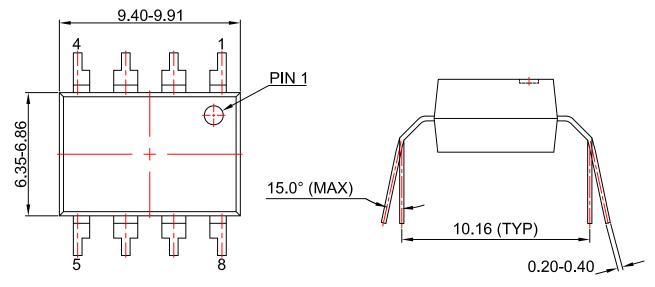
Part Number	Package	Shipping <sup>†</sup>
6N138M DIP 8-Pin (Pb-Free)		50 Units / Tube
6N138SM	SMT 8-Pin (Lead Bend) (Pb-Free)	50 Units / Tube
6N138SDM	SMT 8-Pin (Lead Bend) (Pb-Free)	1,000 Units / Tape & Reel
6N139M	DIP 8-Pin (Pb-Free)	50 Units / Tube
6N139SM	SMT 8-Pin (Lead Bend) (Pb-Free)	50 Units / Tube
6N139SDM	SMT 8-Pin (Lead Bend) (Pb-Free)	1,000 Units / Tape & Reel
6N139VM	DIP 8-Pin, DIN EN/IEC 60747-5-5 Option (Pb-Free)	50 Units / Tube
6N139SVM	SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option (Pb-Free)	
6N139SDVM	SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option (Pb-Free)	1,000 Units / Tape & Reel
6N139TVM	DIP 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option (Pb-Free)	50 Units / Tube
HCPL2730M	DIP 8-Pin (Pb-Free)	50 Units / Tube
HCPL2730SM	SMT 8-Pin (Lead Bend) (Pb-Free)	50 Units / Tube
HCPL2730SDM	SMT 8-Pin (Lead Bend) (Pb-Free)	1,000 Units / Tape & Reel
HCPL2731M	DIP 8-Pin (Pb-Free)	50 Units / Tube
HCPL2731SM SMT 8-Pin (Lead Bend) (Pb-Free)		50 Units / Tube
HCPL2731SDM	SMT 8-Pin (Lead Bend) (Pb-Free)	1,000 Units / Tape & Reel
HCPL2731VM	DIP 8-Pin, DIN EN/IEC 60747-5-5 Option (Pb-Free)	50 Units / Tube

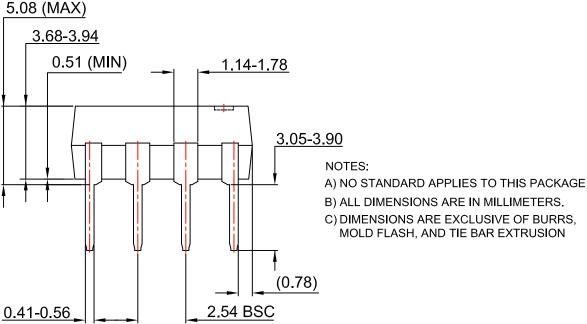
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



#### PDIP8 6.6x3.81, 2.54P CASE 646BW ISSUE O

**DATE 31 JUL 2016** 





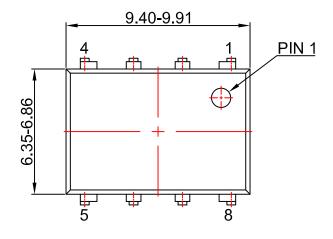
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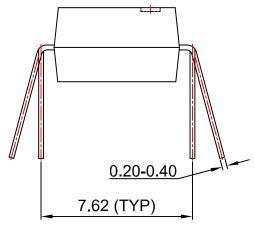
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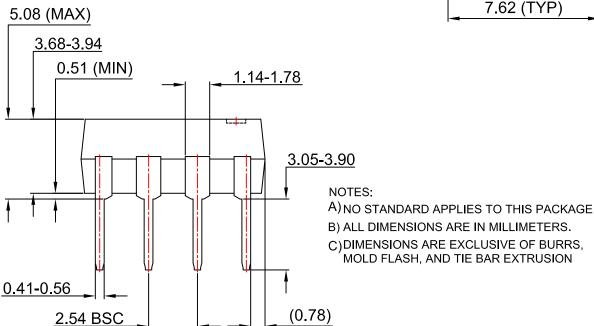


#### PDIP8 9.655x6.6, 2.54P CASE 646CQ ISSUE O

**DATE 18 SEP 2017** 







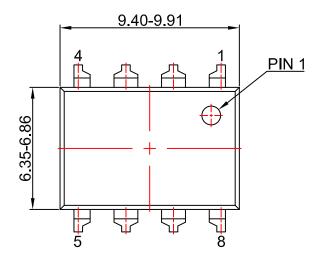
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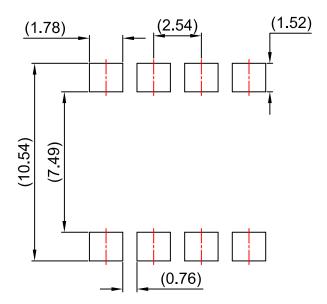
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PDIP8 GW CASE 709AC ISSUE O

**DATE 31 JUL 2016** 





5.08 (MAX)

3.68-3.94

0.51 (MIN)

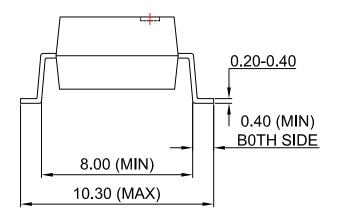
1.14-1.78

(0.78)

2.54BSC

0.41-0.56





#### NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

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